Unit: mm

TOSHIBA Transistor Silicon NPN Triple Diffused Type

2SC6010

High Voltage Switching Applications Switching Regulator Applications DC-DC Converter Applications

• High speed switching: $t_f = 0.24\mu s$ (max) (IC = 0.3A)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V_{CBO}	600	V	
Collector-emitter voltage		V _{CEX}	600	V	
Collector-emitter voltage		V _{CEO}	285	V	
Emitter-base voltage		V _{EBO}	8	V	
Collector current	DC	IC	1.0	Α	
	Pulse	I _{CP}	2.0		
Base current		Ι _Β	0.5	Α	
Collector power dissipation	Ta = 25°C	PC	1.0	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	

7.1MAX
3.8
3.8
3.2
0.555-0.05
0.65
0.45-0.05
1 2 3 1.025±0.05

1. Base
2. Collector
3. Emitter

JEDEC

JEITA

TOSHIBA
2-7D101A

Weight: g (typ.)

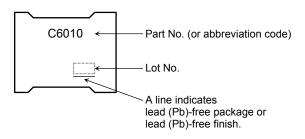
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

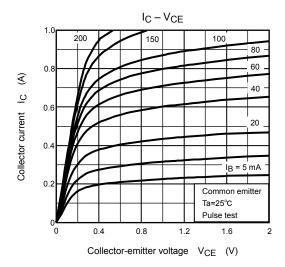
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

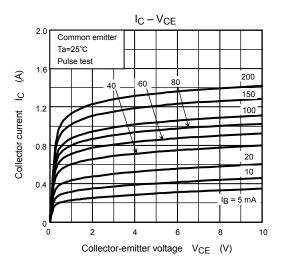
Electrical Characteristics (Ta = 25°C)

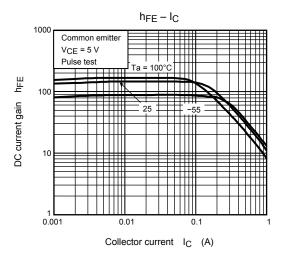
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I _{CBO}	V _{CB} = 600 V, I _E = 0	_	_	100	μΑ
Emitter cut-off current		I _{EBO}	V _{EB} = 8 V, I _C = 0	_	_	100	μA
Collector-base breakdown voltage		V (BR) CBO	I _C = 1 mA, I _B = 0	600	_	_	V
Collector-emitter breakdown voltage		V (BR) CEO	I _C = 10 mA, I _B = 0	285	_	_	V
DC current gain		h _{FE (1)}	V _{CE} = 5 V, I _C = 1 mA	80	_	200	
		h _{FE (2)}	V _{CE} = 5 V, I _C = 0.1 A	100	_	200	
		h _{FE (3)}	V _{CE} = 5 V, I _C = 0.2 A	60	_	_	
Collector emitter saturation voltage		V _{CE (sat)}	I _C = 0.6 A, I _B = 75 mA	_	_	1.0	V
Base-emitter saturation voltage		V _{BE (sat)}	I _C = 0.6 A, I _B = 75 mA	_	_	1.3	V
Switching time	Rise time	t _r	20 μs V _{CC} ≈ 200 V	_	_	0.4	
	Storage time	t _{stg}	INPUT IB1 OUT-PUT	_	_	3.0	μs
	Fall time	t _f	I _{B1} = 20 mA, −I _{B2} = 50 mA DUTY CYCLE ≤ 1%	_	_	0.24	

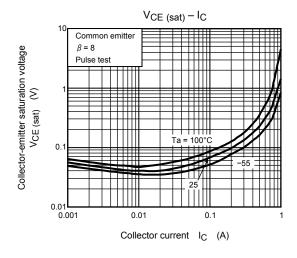
Marking

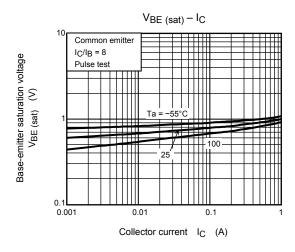


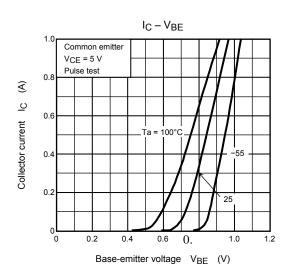




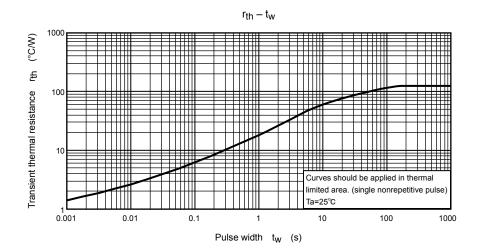


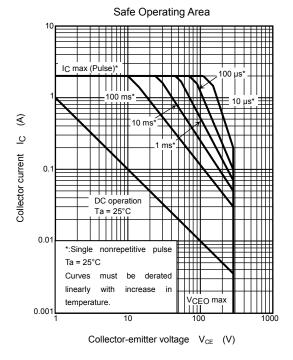


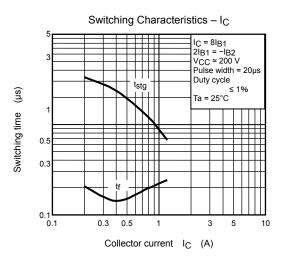


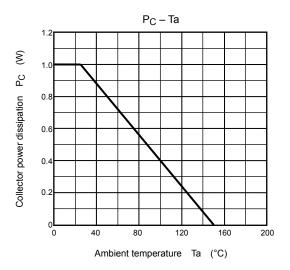


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20070701-EN

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